

Diode AOB210L-AOB298L

VOLTAGE RANGE

30 to 60 Volts

CURRENT

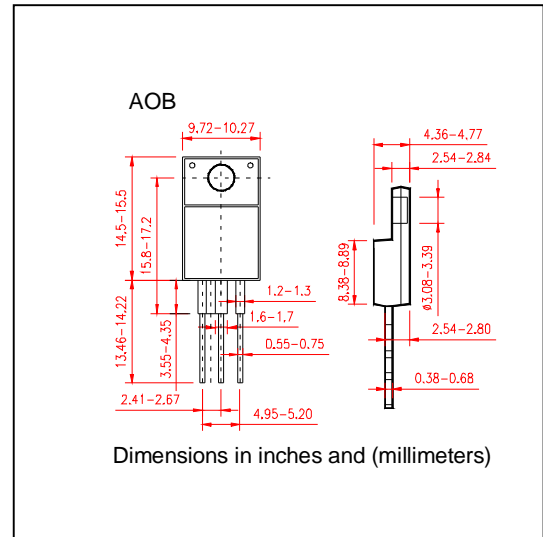
20.0 Amperes

FEATURES

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- Low Power Loss, High efficiency
- High Surge Capability
- High Current capacity and Low Forward Voltage Drop
- For use in low voltage high frequency inverters, Free wheeling, and polarity protection applications
- Plastic Material has UL Flammability Classification 94V-0

MECHANICAL DATA

- Case: ITO-200AB molded plastic
- Terminals: Plated Lead solderable per MIL-STD-202 Method 208
- Polarity: As Marked on Body
- Weight: 2.24 grams (approx)
- Mounting Position: Any
- Marking: Type Number



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

- Single Phase, half wave, 60Hz, resistive or inductive load
- For capacitive load derate current by 20%

	SYMBOLS	AOB210L	AOB254L	AOB262L	AOB282L	AOB292L	AOB298L	UNIT
Peak Repetitive Reverse Voltage	V_{RRM}	30	35	40	45	50	60	V
Working Peak Reverse Voltage	V_{RWM}							
DC Blocking Voltage	V_R							
RMS Reverse Voltage	$V_{R(RMS)}$	21	25	28	32	35	42	V
Average Rectified Output Current (Note 1) @ $T_c=95^\circ\text{C}$	I_O	20.0						A
Non-Repetitive Peak Forward Surge Current 8.3ms single half sine wave superimposed on rated load (JEDEC method)	I_{FSM}	175						A
Forward Voltage Drop @ $I_F=10A, T_c=25^\circ\text{C}$	V_{FM}	0.55				0.75		V
Peak Reverse Current at Rated DC Blocking Voltage	$T_c = 25^\circ\text{C}$	1.0						mA
	$T_c = 100^\circ\text{C}$	50						
Typical Junction Capacitance(Note2)	C_j	650						pF
Typical Resistance Junction to case(Note1)	$R_{\theta JC}$	2.8						$^\circ\text{C}/\text{W}$
Operating and Storage Temperature Range	$T_J T_{STG}$	(-55 to +150)						$^\circ\text{C}$

Notes:

1. Thermal Resistance Junction to case mounted on heatsink
2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC

RATINGE AND CHARACTERISTIC CURVES SRFL2030C THRU SRFL2060C

